

<b>Information Disclosure Citation in an Application</b>	Application No.	Applicant(s)		
	10/788,815	Gordon Ma et al.		
	Docket Number 068736.0230	Group Art Unit 2811	Filing Date February 27, 2004	

**U.S. PATENT DOCUMENTS**

	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
A.	20020179945	12/5/02	Sakamoto et al.	257	288	2/8/02
B.						
C.						
D.						
E.						
F.						
G.						
H.						
I.						
J.						
K.						

**FOREIGN PATENT DOCUMENTS**

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES      NO
L.						
M.						
N.						
O.						
P.						
Q.						
R.						

**NON-PATENT DOCUMENTS**

	DOCUMENT (Including Author, Title, Source, and Pertinent Pages)	DATE
S.	Brech H. et al., "Record Efficiency and Gain at 2.1 GHz of High Power RF Transistors for Cellular and 3G Base Stations", International Electron Devices Meeting, Technical Digest, pages 359-362	12/8/03
T.	International Search Report. PCT/EP2005/001953, 16 pages	Mailing Date 11/28/05
U.	/	

EXAMINER	DATE CONSIDERED
<i>Greg</i>	05-24-06

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.